NSN 5961-00-106-2298

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View Online at https://aerobasegroup.com/nsn/5961-00-106-2298

view Offilite at https://defobasegroup.com/hsh/5501-00-100-2250
Inclosure Material:
Metal
Overall Length:
Between 0.688 inches and 0.797 inches
Overall Diameter:
Between 0.885 inches and 0.915 inches
Mounting Facility Quantity:
1
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Collector
Internal Junction Configuration:
Npn
Mounting Method:
Threaded stud
Features Provided:
Hermetically sealed case
Overall Width Across Flats:
Between 1.047 inches and 1.078 inches
Thread Size:
0.500 inches
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
125.0 collector to base voltage/static/emitter open and 100.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage
static, collector open
Current Rating Per Characteristic:
50.00 amperes collector current, dc
Power Rating Per Characteristic:
350.0 watts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius case
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 1 wire hook

Specification Data:

81349-mil-s-19500/380 government specification

Shelf Life:

N/a

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Demilitarization:

No

Fiig:

A110a0